NSN 5961-01-155-5605

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-155-5605 **Inclosure Material:** Metal **Overall Length:** 1.646 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.544 inches and 0.562 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 breakdown voltage, collector-to-emitter, with specified circuit between base and emitter **Current Rating Per Characteristic:** 35.00 amperes base current, instantaneous horsepower metric **Power Rating Per Characteristic:** 40.0 watts large-signal input power, common-emitter blank **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0